Diode Semiconductor Device - Page 1 of 1



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# Inclosure Material:

Glass

# Overall Length:

Between 0.125 inches and 0.250 inches

## Terminal Length:

Between 0.700 inches and 1.300 inches

## **Overall Diameter:**

Between 0.065 inches and 0.085 inches

## Mounting Method:

Terminal

## Criticality Code Justification:

Feat

Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

160.0 breakdown voltage, dc and 150.0 working peak reverse voltage

### Current Rating Per Characteristic:

6.00 amperes forward current, average absolute and 125.00 amperes forward current, average preset

## Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

## **Special Features:**

Nuclear hardness critical item; junction pattern arrangement: pn

### Terminal Type And Quantity:

2 uninsulated wire lead

# Shelf Life:

N/a

#### Unit Of Measure:

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### Demilitarization:

No

## Fiig:

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